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#### **Inclosure Material:**

Metal

**Overall Length:** 

1.550 inches

## **Overall Height:**

0.300 inches

**Overall Width:** 

1.050 inches

#### **Mounting Facility Quantity:**

2

#### Internal Configuration:

Junction contact

### Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

#### **Mounting Method:**

Unthreaded hole

# Features Provided:

Hermetically sealed case

### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

400.0 collector to emitter voltage/static/base open and 550.0 collector to emitter reverse voltage and 600.0 collector to base voltage/static/emitter open and 8.0 emitter to base voltage, static, collector open

### **Current Rating Per Characteristic:**

10.00 amperes source cutoff current and 2.00 amperes source cutoff current

### **Power Rating Per Characteristic:**

175.0 watts small-signal input power, common-collector absolute

**Transfer Ratio:** 

300.0 static forward current transfer ratio, common-emitter

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

# **Special Features:**

Junction pattern arrangement: npn

# **Terminal Type And Quantity:**

2 pin and 1 case

# Shelf Life:

N/a

Unit Of Measure:

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### Demilitarization:

No

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